

A different view of the quantum Hall plateau-to-plateau transitions

D. Shahar, D. C. Tsui and M. Shayegan

Department of Electrical Engineering, Princeton University, Princeton New Jersey, 08544

E. Shimshoni

Department of Mathematics-Physics, Oranim-Haifa University, Tivon 36006, Israel

S. L. Sondhi

Department of Physics, Princeton University, Princeton New Jersey, 08544

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Abstract

We demonstrate experimentally that the transitions between adjacent integer quantum Hall (QH) states are equivalent to a QH-to-insulator transition occurring in the top Landau level, in the presence of an inert background of the other completely filled Landau levels, each contributing a single unit of quantum conductance, e^2/h , to the total Hall conductance of the system.

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One of the most active topic of research in the field of two dimensional electron systems has been the study of the transition regions separating adjacent quantum Hall (QH) states [1–6]. These transition regions were considered mainly in the theoretical framework of scaling [6,7], extending to the high magnetic field (B) QH regime a methodology that was originally developed for the study of the $B = 0$ metal-insulator transition [8].

A comprehensive experimental study by Wei and his collaborators [1] revealed much of the fascinating physics of these transitions. By focusing on the diagonal resistivity (ρ_{xx}) peaks separating adjacent QH minima, and on the Hall resistivity (ρ_{xy}) steps accompanying them, they were able to show that in the transition regions, the conduction process can be well-described by that expected of a system near a critical point of a quantum phase transition. Two of their experimental findings particularly support a quantum-critical description of these transitions; both were obtained from a study of the evolution of the width of the ρ_{xx} peaks, ΔB , and the maximal slope of the ρ_{xy} steps, $(\frac{d\rho_{xy}}{dB})^{max}$, as a function of temperature, T . Their first result was that the width and inverse-slope approach zero as $T \rightarrow 0$,

$$\Delta B, (\frac{d\rho_{xy}}{dB})^{-1}_{max} \sim T^{\kappa}, \quad (1)$$

suggestive of proximity to a scale-invariant critical point at a critical field $B = B_c$ and $T = 0$. Their second observation was that the value of κ is independent of which Landau level (LL) is involved (for spin split LL's), and was also the same, within error, for many samples studied. This *universality* is another expected signature of a quantum phase transition [6].

More recently, another class of transitions in the quantum Hall regime were studied [9–12]. These B -driven transitions are not between adjacent QH states. Rather, they are transitions from QH states to the insulating phase that terminates the QH series. Since, in the insulator, $\rho_{xx} \rightarrow \infty$, these transitions are not characterized by a ρ_{xx} peak, and experimentally they appear, on first sight, to be different from the inter-QH, plateau-to-plateau transitions. It was soon realized, however, that a critical B exists for these transitions as well and that universal scaling behavior is also observed in their vicinity, characterized by a critical exponent that is consistent with the κ obtained for the inter-QH transitions

[12,13]. For these QH-to-insulator transitions, there is significant experimental evidence in support of the existence of the theoretically expected [14] universal critical amplitude, with the ρ_{xx} value at the transition point close to h/e^2 [11,12]. This should be contrasted with the inter-QH transitions, for which most researchers report a critical amplitude that is not only significantly (40 – 80%) smaller than the theoretically expected value, but in many cases is also T -dependent [15].

From a theoretical standpoint, the transitions to the insulator are similar to the inter-QH transitions; both occur as the fermi energy crosses the extended states that exist in the center of a LL. They differ, however, in that the inter-QH transitions take place in the presence of a number of filled LLs underneath the fermi energy, separated by a gap from the top LL where the action takes place. If one assumes that the only contribution of the background LLs is to the Hall conductance, each filled LL adding e^2/h to the measured value of σ_{xy} , it may be possible, by numerically removing that contribution from the experimental data, to test this equivalence. There is an equivalent scenario involving fractional QH states, in which the transitions take the form of a QH-to-insulator transition of a set of quasiparticles in parallel with a background (parent) QH liquid. This insight has been systematized theoretically [16], and the general idea of relating the transitions in the integer and fractional regimes has been corroborated by recent experiments [11,12]. In this paper we will only be concerned with integer QH transitions.

The purpose of this communication is to report on an experimental test of the conjecture that the inter-QH and the QH-to-insulator transitions are indeed similar. For simplicity, we focus on the transition from the $\nu = 2$ to $\nu = 1$ integer QH states (dubbed $2 - 1$), which occurs at the top spin-split first LL, and compare it to the $\nu = 1$ -to-insulator ($1 - 0$) transition in the same sample, which takes place near the center of the lower spin-split first LL. To implement this comparison, we utilized a straightforward scheme, as follows. First, we obtain traces of ρ_{xx} and ρ_{xy} for the $2 - 1$ transition using a Hall-bar shaped sample etched in a high-density ($n = 2.27 \cdot 10^{11} \text{ cm}^{-2}$), low-mobility ($\mu = 10.8 \cdot 10^3 \text{ cm}^2/\text{Vsec}$), MBE grown GaAs/AlGaAs wafer. These resistivity traces, taken at several T 's, are plotted in Fig. 1a.

The transition is typified by a ρ_{xx} peak that widens with T and by the accompanying step in ρ_{xy} . Next, we convert the ρ 's to σ 's using the standard matrix conversion,

$$\sigma_{xx(xy)} = \frac{\rho_{xx(xy)}}{\rho_{xx}^2 + \rho_{xy}^2} \quad (2)$$

and plot the σ traces in Fig. 1b. We then obtain the conductivity of the topmost LL by subtracting from the conductivity data the contribution of the lowest, full LL:

$$\sigma_{xx}^t = \sigma_{xx} \quad (3)$$

$$\sigma_{xy}^t = \sigma_{xy} - e^2/h \quad (4)$$

assuming, as mentioned, that the only contribution of the lowest LL is e^2/h to the Hall conductivity (Throughout this paper, the index t refers to the contribution of the topmost LL to the transport coefficients). Next we convert σ_{xx}^t and σ_{xy}^t to new resistivities, ρ_{xx}^t and ρ_{xy}^t , which are the resistivities of the topmost LL. This completes our procedure, and we are now ready for the comparison with the data obtained from the $1 - 0$ transition in the same sample.

The comparison is made in Fig. 2, where we plot ρ_{xx}^t (solid lines) and ρ_{xy}^t (short-dashed lines) as a function of ν for the $2 - 1$ transition (Fig. 2a), and traces of ρ_{xx} and ρ_{xy} vs. ν obtained from the same sample near the $1 - 0$ transition terminating the QH series, in Fig 2b (here, of course, $\rho^t = \rho$). While for the ρ_{xx} traces in both graphs of Fig. 2 we present data at our lowest T range ($T < 150$ mK), the ρ_{xy} traces shown were taken at an elevated T (≈ 320 mK) for which reliable data can be obtained. The difficulties with the Hall component data at lower T 's, shown in Fig. 3, will be discussed below.

The first point that can be observed in Fig. 2 is the clear similarity of the overall appearance of the traces in the two graphs. In particular, both sets of ρ_{xx} traces are characterized by a T -independent crossing point of the traces taken at different T 's which, for the $1 - 0$ transition, has been identified as the QHE-to-insulator transition point. [10,11] Building on the similarity of the traces obtained from the different transitions, it is natural to associate

the $2 - 1$ transition ν , ν_c , with the crossing point of the ρ_{xx}^t traces observed in Fig 2a. Adopting this identification of ν_c , we proceed to explore its consequences on the ρ and σ traces of Fig. 1. We wish to emphasize that the similarity also holds for the ρ_{xy} traces, both remaining nearly constant through the transition region, and near their quantized value of h/e^2 [18,17]. We also note that initial search for duality symmetry [17–19] for the resistivities of the top LL showed that ρ_{xx}^t indeed exhibit duality symmetry for the $2 - 1$ transition.

First, we note that the transition ν is *not* at the ρ_{xx} peak (the dashed line in Fig. 1 marks ν_c). In fact, the position of the ρ_{xx} peak is clearly T dependent, at the same T range where the crossing point in ρ_{xx}^t (see Fig. 2b) is not. Instead, a T -independent point can be seen at the high- ν shoulder of the ρ_{xx} peaks. It is this point, rather than the peak's center, that coincides with the transition as inferred from the ρ_{xx}^t traces. On the other hand, inspecting the σ_{xx} traces in Fig. 1b reveals that the σ_{xx} peak is centered around ν_c , and its position is much less T -dependent. One can immediately draw the following conclusions: a) associated with the $2 - 1$ transition is a σ_{xx} peak, whose position is T -independent (at low T), and is centered around ν_c , b) a peak in ρ_{xx} also exist in the vicinity of the transition, but its center is offset by a T -dependent amount from ν_c , and c) on the ρ_{xx} peak, the transition point is characterized by a T -independent point located at its shoulder. The fact that only one of either the ρ_{xx} or the σ_{xx} peak is symmetric is hardly surprising because obtaining one from the other involves the distinctly asymmetric Hall component. Here, we demonstrate that at low T , the σ_{xx} peak is the symmetric one.

Inspecting Fig. 1, one can identify the existence of crossing points in the Hall components, σ_{xy} and ρ_{xy} . For the σ_{xy} 's, the value at the crossing point is close to the mid-value between the two QHE plateaus [14], but for the ρ_{xy} 's it is not so, with the transition point clearly at much lower value. The ν position of these crossing points coincides with ν_c , as it is identified from the crossing points of the ρ_{xx} traces. As we noted in previous works [17–19], there appear to be a new relation between the diagonal and Hall transport coefficients near QH transitions. This relation implies that ρ_{xy}^t remains constant and equal to its quantized value across the transition, into the insulating phase. Our experimental observations are in

support of a constant ρ_{xy} near both, the $1 - 0$ transition, and the $1/3$ -fractional QH to insulator transition. The constancy of the ρ_{xy}^t trace of Fig. 2a provides further evidence to the equivalence of the $1 - 0$ and $2 - 1$ transitions. An equivalent way of expressing this relation that easily lends itself to a more detailed experimental test, was put forth by Ruzin and his co-workers [20]. Their results are cast in the form of a ‘semicircle’ law for the conductivities:

$$(\sigma_{xx}^t)^2 + (\sigma_{xy}^t)^2 = \sigma_{xy}^t. \quad (5)$$

To test this we plot, in Fig. 3, σ_{xy}^t vs. $(\sigma_{xx}^t)^2 + (\sigma_{xy}^t)^2$ for traces obtained at several T ’s from 26–222 mK. Overall, the data follow the expected straight line at higher T ’s, with systematic deviations at low σ_{xy} that becomes more significant as T is lowered. At present, we can not unambiguously delineate the source of these deviations [17]; whether the semicircle law correctly describes the QH transitions as $T \rightarrow 0$, or is just an approximation applicable at higher T ’s, is outside the reach of the current experiment.

So far we discussed the similarity of the $2 - 1$ and $1 - 0$ transitions on a qualitative level. In order to extend our discussion in a more precise way, we now address the quantitative parameters describing the transitions, namely the critical exponents and amplitudes. In Fig. 4 we present a scaling analysis of our ρ_{xx} data for both transitions. Using a scaling procedure similar to that used by Wong et al. [12] we plot ρ_{xx} for the $1 - 0$ transition (Fig. 3a) and ρ_{xx}^t for the $2 - 1$ transition (Fig 3b) versus the scaling argument, $(\nu - \nu_c)/T^\kappa$. While ν_c can be directly obtained from the data, we vary the value of κ until we obtain the optimal “collapse” of the ρ_{xx} traces obtained at different T ’s. The resulting values of the critical exponent, $\kappa = 0.45 \pm 0.05$, are the same for both transitions and are also in good agreement with results obtained in previous studies of QHE transitions [1,12]. It is worthwhile to re-emphasize the ubiquitous nature of κ , and its independence of the number of filled LL where the transition takes place.

Another quantitative aspect of the transitions is their critical resistivity. Both transitions depicted in Fig. 2 have a value of the critical resistivity at B_c close to h/e^2 , again in good agreement with studies of the $1 - 0$ transitions [11]. As mentioned before, the issue of the

universal critical resistivities for the inter-QHE is still under debate. One may argue that the process of eliminating the contribution of the lowest LL from the $2 - 1$ data may result in an incorrect critical resistivity value for the ρ_{xx}^t obtained for that transition. To alleviate this concern we carefully inspect the raw ρ_{xx} data presented in Fig. 1a. We recall that the scaling theory of the QH transitions predicts not one, but two, distinct universal critical amplitudes for the $2 - 1$ transition. The first is ρ_{xx}^c , the value of ρ_{xx} at B_c , and the second is ρ_{xx}^p , the peak value of ρ_{xx} which, as discussed above, is distinct from ρ_{xx}^c . As can be seen, both are T -independent at the low- T range shown, with $\rho_{xx}^c = 4.4 \text{ k}\Omega$ and $\rho_{xx}^p = 6.25 \text{ k}\Omega$. Both these values are within 20% of the expected [21] values of $\frac{h}{5e^2}$ and $\frac{h}{4e^2}$, respectively, lending further support to the universal character of the transitions.

To summarize, in this work we have demonstrated the equivalence of the inter-QH, plateau-to-plateau transitions, to the QH-to-insulator transition that terminates the QH series, and tested the proposed semicircle relation between the longitudinal and Hall components of the conductivity tensor near the transitions.

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- [21] In the critical region the resistivities are expected to be universal functions of the combination $(B - B_c)/T^{1/\nu z}$. Assuming that the non-universal amplitude multiplying this combination is the same for both components, it follows that ρ_{xx} is a universal function of ρ_{xy} . The form of this function is fixed if the semi-circle law is assumed and can be seen to lead to the maximum value $\rho_{xx}^p = \frac{h}{4e^2}$ [20]. Additionally, $\rho_{xx}^c = \frac{h}{5e^2}$ follows from generalizing the lowest Landau level results of Ref. [14] to the second LL.

FIGURES

FIG. 1. (a) ρ_{xx} (lower curves) and ρ_{xy} vs. ν taken in the vicinity of the $\nu = 2$ to 1 transition, at $T = 42, 70, 101$ and 137 mK. Note the narrowing of the transitions as T is lowered. (b) σ_{xx} and σ_{xy} vs. ν , calculated from (a). Dashed line in both (a) and (b) indicates ν_c , inferred from the data in Fig. 2a (see text).

FIG. 2. (a) ρ_{xx}^t (solid lines) and ρ_{xy}^t (long-dashed line) for the $2 - 1$ transition, calculated from the data in Fig. 1a. The T for the ρ_{xx}^t data are $42, 70, 101$ and 137 mK, and for the ρ_{xy}^t trace $T = 330$ mK. (b) Measured ρ_{xx} (solid lines) and ρ_{xy} (long-dashed line) for the $1 - 0$ transition. The T for the ρ_{xx} data are $42, 84, 106$ and 145 mK, and for the ρ_{xy} trace $T = 323$ mK. Dashed line in both (a) and (b) indicates the transition ν inferred from the common crossing point of the ρ_{xx}^t (or ρ_{xx}) traces.

FIG. 3. A plot of σ_{xy}^t vs. $(\sigma_{xx}^t)^2 + (\sigma_{xy}^t)^2$ for the $2 - 1$ transition. A straight line indicates a semicircle relation between the conductivity components.

FIG. 4. A scaling analysis of the ρ_{xx}^t (a) ρ_{xx} (b) data in Figs. 2a and 2b, respectively. The scaling exponent κ , is determined to within 20%.







